

2EDF7275KXUMA2

Data Sheet

Fast, robust, dual-channel, functional isolated MOSFET gate drivers with accurate and stable timing

Manufacturers <u>Infineon Technologies Corporation</u>

Package/Case PG-TFLGA-13

Product Type Integrated Circuits (ICs)

RoHS

Lifecycle



Images are for reference only

Please submit RFQ for 2EDF7275KXUMA2 or Email to us: sales@ovaga.com We will contact you in 12 hours.

RFO

General Description

The EiceDRIVERTM 2EDF72x5K is a functional isolated gate driver designed for high-performance DC-DC medium-voltage, half- and full-bridge topologies. The 4A/8A source/sink currents, combined with a low 37ns propagation delay and the highly accurate timing over both temperature and production, are the perfect fit for high-frequency PWM control with tightest possible dead time windows, delivering highest conversion efficiency.

The very low impedance of the gate driver output stages keeps the driver package and PCB cooler, which is a key benefit in high density power brick converters. The device's 4V UVLO and dead time control ensure that OptiMOSTM half-bridge MOSFETs always run within their safe operating area. A CMTI of 150V/ns guarantees high robustness even for fast switching transients (di/dt) in the power loop. The EiceDRIVERTM 2EDF7235K includes programmable DTC (dead time control) and an inverted SLDOP mode. All devices can operate in low cost bootstrapped high side supply and come in a cost competitive, small form factor LGA13 5mm x 5mm package.

Features Application

Fast power switching with accurate timing Telecom DC-DC

Optimized for area and low cost system BOM Server

Robust design against switching noise Industrial SMPS

Output- to-output channel isolation UPS

Input-to-output channel isolation Battery

Efficiency gain and lower losses EV-Charging

Improved thermal behavior at smaller form factor

Protection and safe operation

Flexible configurations

Regulatory safety

Enabling higher system e iciency and higher power density designs

Improving cost position, integration and mass manufacturability

Extending end-product lifetime by improving safe operation of power switches and reliable PWM communication and PWM signal chain in abnormal conditions

Lowering EMI by ground isolation, driver proximity to MOSFETs or use of Kelvin Source MOSFETs

Meeting all isolation requirements of standard DC-DC equipment

Related Products



BTS442E2-E3062A

Infineon Technologies Corporation TO263



SAK-C504-2E24M

Infineon Technologies Corporation MQFP-44



BTS50452EKA

Infineon Technologies Corporation SOP-14



BTT6030-2EKA

Infineon Technologies Corporation SOP-14



BSP452E6327

Infineon Technologies Corporation SOT223-4



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Infineon Technologies Corporation BGA388

BTT6030-2ERA

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BTS5030-2E

Infineon Technologies Corporation SOP-14